

**TC74AC574P,TC74AC574F,TC74AC574FW,TC74AC574FT****Octal D-Type Flip-Flop with 3-State Output**

The TC74AC574 is an advanced high speed CMOS OCTAL FLIP-FLOP fabricated with silicon gate and double-layer metal wiring C<sup>2</sup>MOS technology.

It achieves the high speed operation similar to equivalent Bipolar Schottky TTL while maintaining the CMOS low power dissipation.

These 8-bit D-type flip-flops are controlled by a clock input (CK) and a output enable input ( $\overline{OE}$ ).

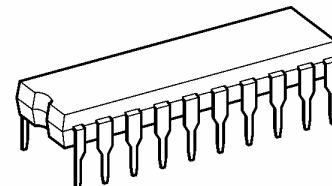
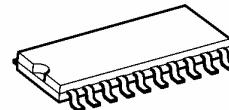
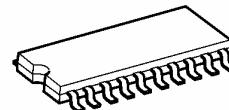
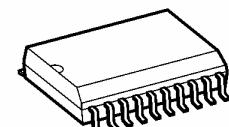
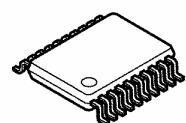
When the  $\overline{OE}$  input is high, the eight outputs are in a high impedance state.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

**Features**

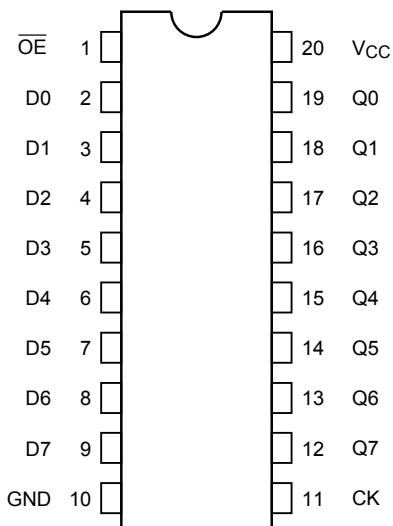
- High speed:  $f_{max} = 180$  MHz (typ.) at  $V_{CC} = 5$  V
- Low power dissipation:  $I_{CC} = 8$   $\mu$ A (max) at  $T_a = 25^\circ C$
- High noise immunity:  $V_{NIH} = V_{NIL} = 28\%$   $V_{CC}$  (min)
- Symmetrical output impedance:  $|I_{OH}| = I_{OL} = 24$  mA (min)  
Capability of driving 50  $\Omega$  transmission lines
- Balanced propagation delays:  $t_{PLH} \approx t_{PHL}$
- Wide operating voltage range:  $V_{CC}$  (opr) = 2 to 5.5 V
- Pin and function compatible with 74F574

Note: xxxFW (JEDEC SOP) is not available in Japan.

**TC74AC574P****DIP20-P-300-2.54A****TC74AC574F****SOP20-P-300-1.27A****SOP20-P-300-1.27****TC74AC574FW****SOL20-P-300-1.27****TC74AC574FT****TSSOP20-P-0044-0.65A**

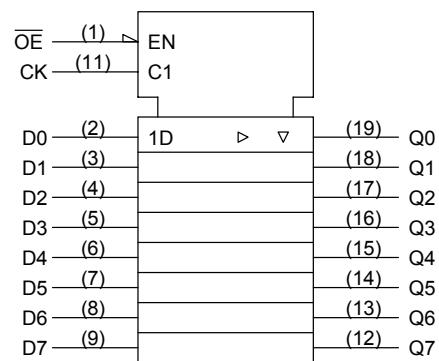
Weight	
DIP20-P-300-2.54A	: 1.30 g (typ.)
SOP20-P-300-1.27A	: 0.22 g (typ.)
SOP20-P-300-1.27	: 0.22 g (typ.)
SOL20-P-300-1.27	: 0.46 g (typ.)
TSSOP20-P-0044-0.65A	: 0.08 g (typ.)

## Pin Assignment



(top view)

## IEC Logic Symbol



## Truth Table

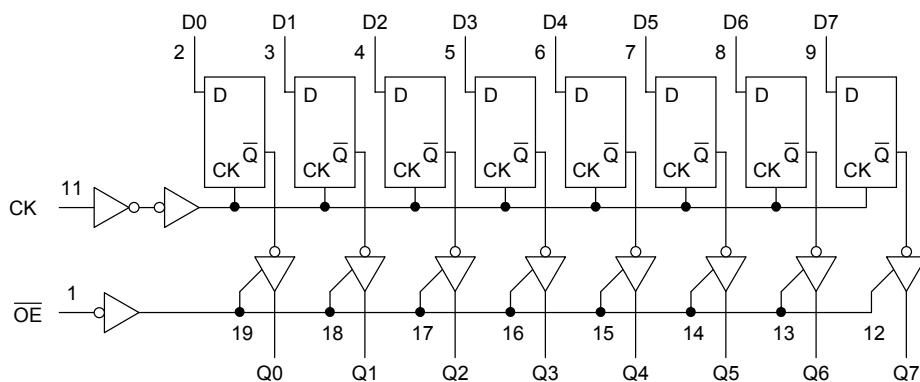
Inputs			Output
$\overline{OE}$	CK	D	Q
H	X	X	Z
L	↓	X	$Q_n$
L	↑	L	L
L	↑	H	H

X: Don't care

Z: High impedance

 $Q_n$ : No change

## System Diagram



**Absolute Maximum Ratings (Note 1)**

Characteristics	Symbol	Rating	Unit
Supply voltage range	$V_{CC}$	-0.5 to 7.0	V
DC input voltage	$V_{IN}$	-0.5 to $V_{CC} + 0.5$	V
DC output voltage	$V_{OUT}$	-0.5 to $V_{CC} + 0.5$	V
Input diode current	$I_{IK}$	$\pm 20$	mA
Output diode current	$I_{OK}$	$\pm 50$	mA
DC output current	$I_{OUT}$	$\pm 50$	mA
DC $V_{CC}$ /ground current	$I_{CC}$	$\pm 200$	mA
Power dissipation	$P_D$	500 (DIP) (Note 2)/180 (SOP/TSSOP)	mW
Storage temperature	$T_{stg}$	-65 to 150	°C

Note1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Note2: 500 mW in the range of  $T_a = -40$  to  $65^\circ\text{C}$ . From  $T_a = 65$  to  $85^\circ\text{C}$  a derating factor of  $-10 \text{ mW}/^\circ\text{C}$  should be applied up to 300 mW.

**Recommended Operating Conditions (Note)**

Characteristics	Symbol	Rating	Unit
Supply voltage	$V_{CC}$	2.0 to 5.5	V
Input voltage	$V_{IN}$	0 to $V_{CC}$	V
Output voltage	$V_{OUT}$	0 to $V_{CC}$	V
Operating temperature	$T_{opr}$	-40 to 85	°C
Input rise and fall time	$dt/dV$	0 to 100 ( $V_{CC} = 3.3 \pm 0.3 \text{ V}$ ) 0 to 20 ( $V_{CC} = 5 \pm 0.5 \text{ V}$ )	ns/V

Note: The recommended operating conditions are required to ensure the normal operation of the device.  
Unused inputs must be tied to either  $V_{CC}$  or  $GND$ .

## Electrical Characteristics

## DC Characteristics

Characteristics	Symbol	Test Condition		Ta = 25°C			Ta = -40 to 85°C		Unit	
				V <sub>CC</sub> (V)	Min	Typ.	Max	Min		
High-level input voltage	V <sub>IH</sub>	—		2.0	1.50	—	—	1.50	—	V
				3.0	2.10	—	—	2.10	—	
				5.5	3.85	—	—	3.85	—	
Low-level input voltage	V <sub>IL</sub>	—		2.0	—	—	0.50	—	0.50	V
				3.0	—	—	0.90	—	0.90	
				5.5	—	—	1.65	—	1.65	
High-level output voltage	V <sub>OH</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -50 µA	2.0	1.9	2.0	—	1.9	—	V
				3.0	2.9	3.0	—	2.9	—	
			I <sub>OH</sub> = -4 mA	4.5	4.4	4.5	—	4.4	—	
				3.0	2.58	—	—	2.48	—	
Low-level output voltage	V <sub>OL</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub>	I <sub>OH</sub> = -24 mA	4.5	3.94	—	—	3.80	—	V
				5.5	—	—	—	3.85	—	
			I <sub>OH</sub> = -75 mA (Note)	2.0	—	0.0	0.1	—	0.1	
				3.0	—	0.0	0.1	—	0.1	
			I <sub>OL</sub> = 50 µA	4.5	—	0.0	0.1	—	0.1	
				5.5	—	—	—	—	0.1	
3-state output off-state current	I <sub>OZ</sub>	V <sub>IN</sub> = V <sub>IH</sub> or V <sub>IL</sub> V <sub>OUT</sub> = V <sub>CC</sub> or GND	I <sub>OL</sub> = 12 mA	3.0	—	—	0.36	—	0.44	V
				4.5	—	—	0.36	—	0.44	
Input leakage current	I <sub>IN</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND	I <sub>OL</sub> = 24 mA	5.5	—	—	—	—	1.65	V
				5.5	—	—	—	—	—	
Quiescent supply current	I <sub>CC</sub>	V <sub>IN</sub> = V <sub>CC</sub> or GND		5.5	—	—	8.0	—	80.0	µA

Note: This spec indicates the capability of driving 50 Ω transmission lines.

One output should be tested at a time for a 10 ms maximum duration.

Timing Requirements (input: t<sub>r</sub> = t<sub>f</sub> = 3 ns)

Characteristics	Symbol	Test Condition			Ta = 25°C	Ta = -40 to 85°C	Unit
					Limit	Limit	
Minimum pulse width (CK)	t <sub>w</sub> (H) t <sub>w</sub> (L)	—		3.3 ± 0.3	7.0	7.0	ns
				5.0 ± 0.5	5.0	5.0	
Minimum set-up time	t <sub>s</sub>	—		3.3 ± 0.3	9.0	9.0	ns
				5.0 ± 0.5	4.5	4.5	
Minimum hold time	t <sub>h</sub>	—		3.3 ± 0.3	1.0	1.0	ns
				5.0 ± 0.5	1.0	1.0	

AC Characteristics ( $C_L = 50 \text{ pF}$ ,  $R_L = 500 \Omega$ , input:  $t_r = t_f = 3 \text{ ns}$ )

Characteristics	Symbol	Test Condition	Ta = 25°C			Ta = -40 to 85°C		Unit
			V <sub>CC</sub> (V)	Min	Typ.	Max	Min	
Propagation delay time (CK-Q)	t <sub>pLH</sub>	—	3.3 ± 0.3	—	9.8	16.7	1.0	19.0
	t <sub>pHL</sub>		5.0 ± 0.5	—	6.1	9.2	1.0	10.5
Output enable time	t <sub>pZL</sub>	—	3.3 ± 0.3	—	9.2	15.8	1.0	18.0
	t <sub>pZH</sub>		5.0 ± 0.5	—	6.1	9.3	1.0	10.6
Output disable time	t <sub>pLZ</sub>	—	3.3 ± 0.3	—	6.6	11.0	1.0	12.5
	t <sub>pHZ</sub>		5.0 ± 0.5	—	5.8	8.8	1.0	10.0
Maximum clock frequency	f <sub>max</sub>	—	3.3 ± 0.3	50	100	—	50	MHz
			5.0 ± 0.5	95	160	—	95	
Input capacitance	C <sub>IN</sub>	—	—	—	5	10	—	10
Output capacitance	C <sub>OUT</sub>	—	—	—	10	—	—	pF
Power dissipation capacitance	C <sub>PD</sub>		(Note)	—	36	—	—	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

$$I_{CC \text{ (opr)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/8 \text{ (per F/F)}$$

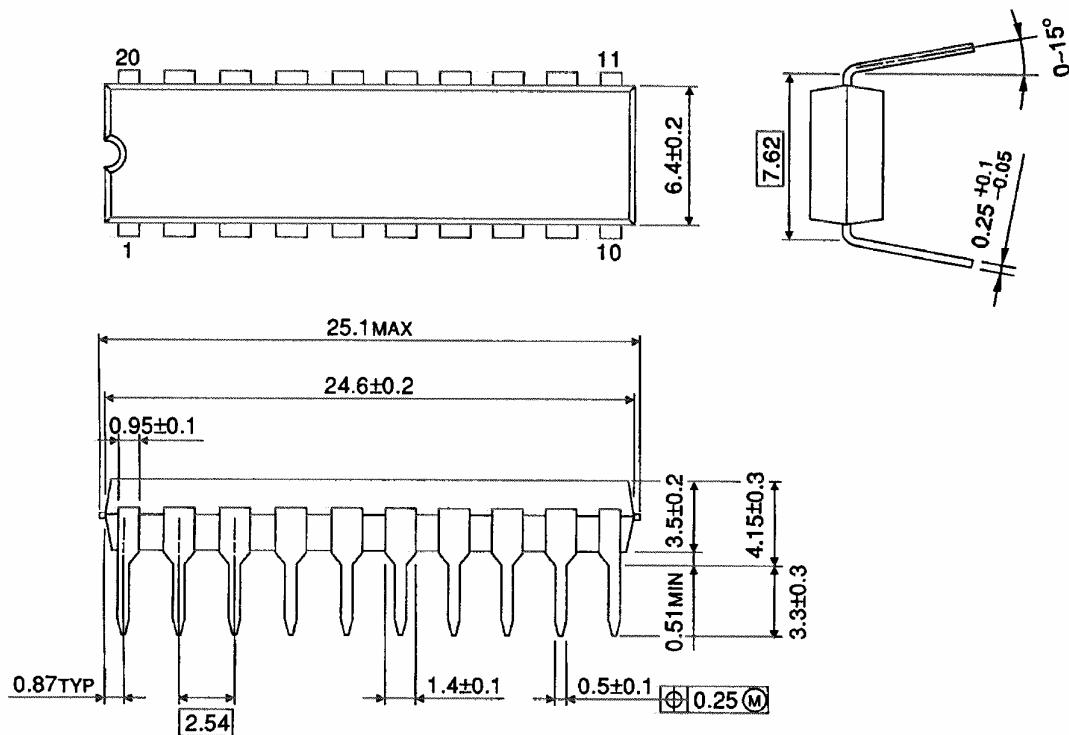
And the total C<sub>PD</sub> when n pcs. of latch operate can be gained by the following equation:

$$C_{PD \text{ (total)}} = 26 + 10 \cdot n$$

**Package Dimensions**

DIP20-P-300-2.54A

Unit : mm

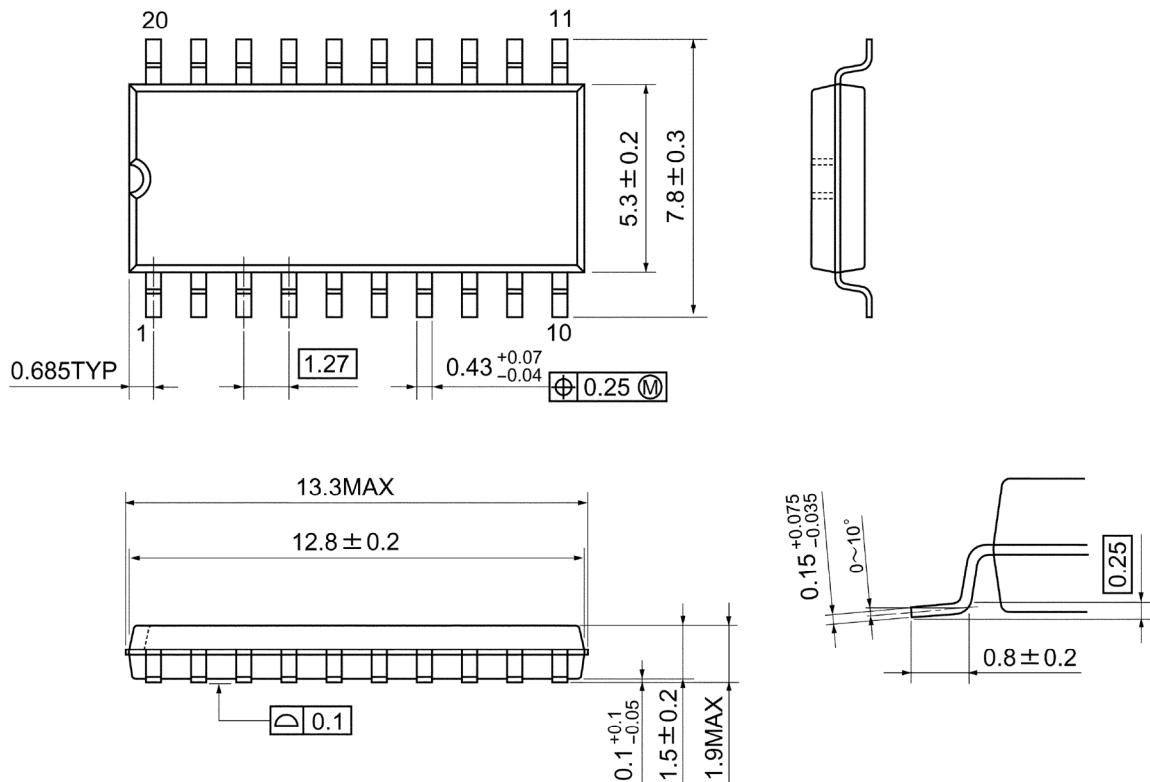


Weight: 1.30 g (typ.)

**Package Dimensions**

SOP20-P-300-1.27A

Unit: mm

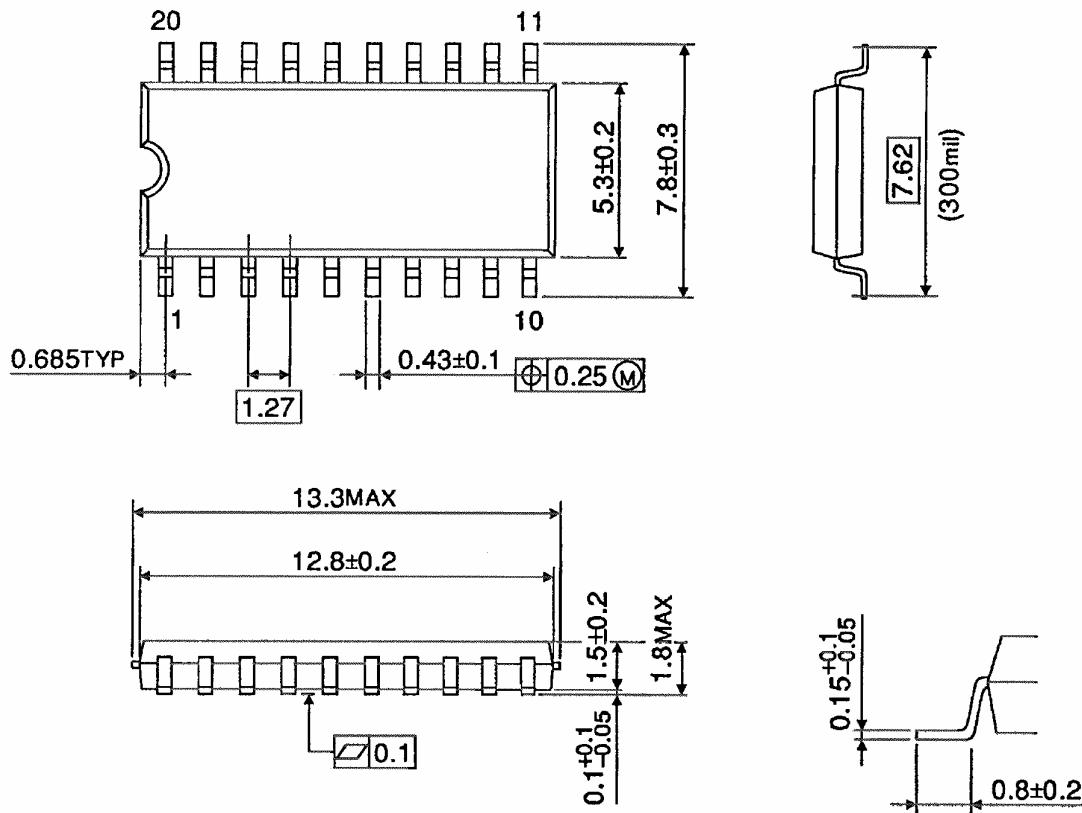


Weight: 0.22 g (typ.)

**Package Dimensions**

SOP20-P-300-1.27

Unit : mm

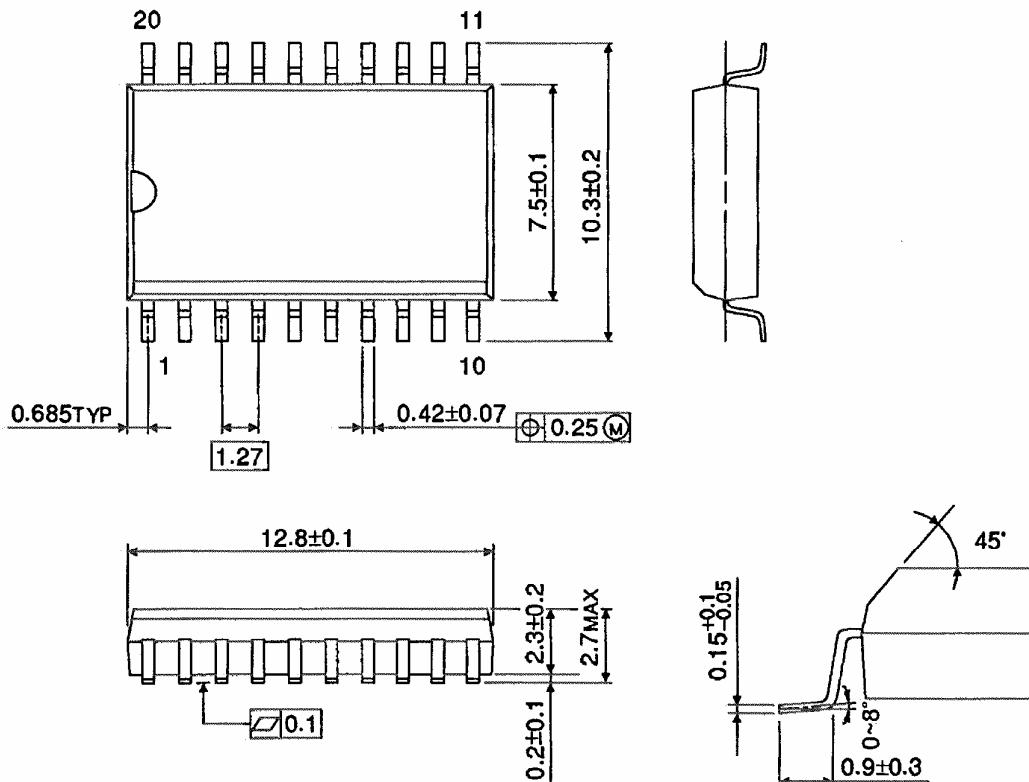


Weight: 0.22 g (typ.)

**Package Dimensions (Note)**

SOL20-P-300-1.27

Unit : mm



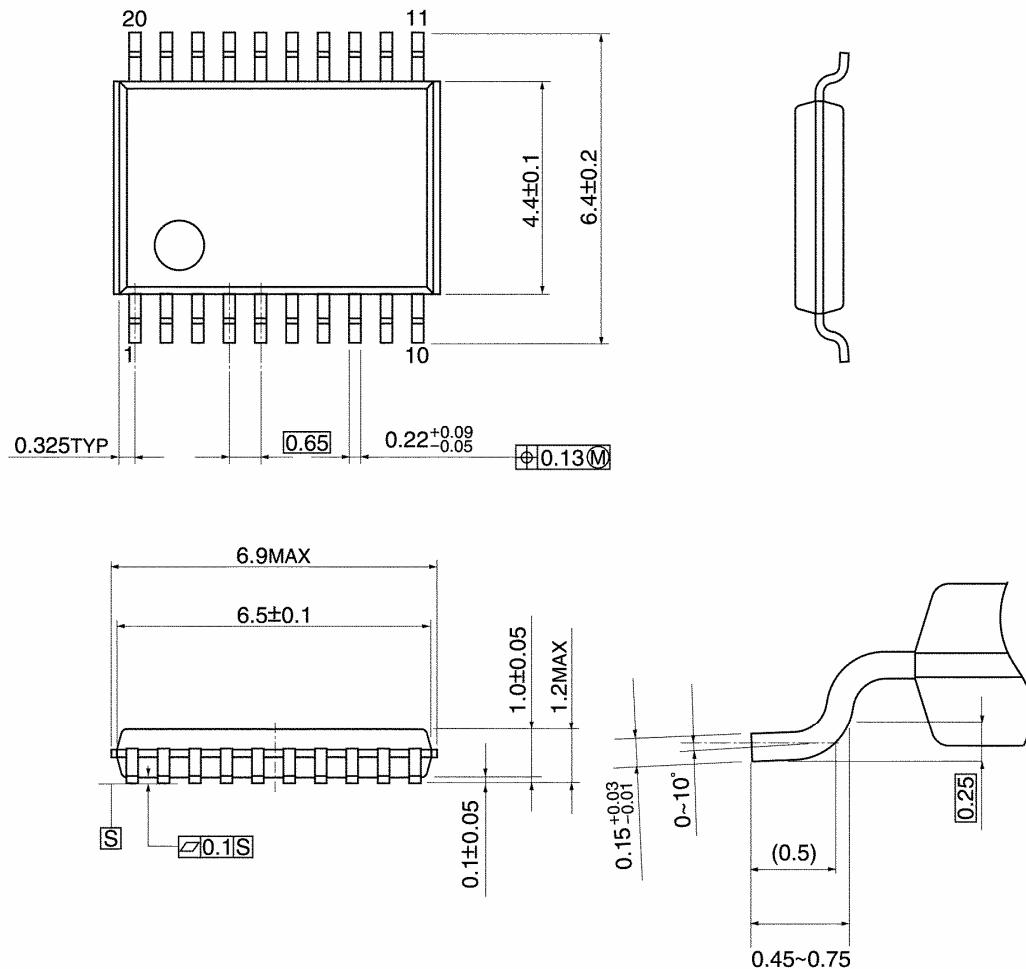
Note: This package is not available in Japan.

Weight: 0.46 g (typ.)

**Package Dimensions**

TSSOP20-P-0044-0.65A

Unit: mm



Weight: 0.08 g (typ.)

**Note: Lead (Pb)-Free Packages****DIP20-P-300-2.54A SOP20-P-300-1.27A TSSOP20-P-0044-0.65A****RESTRICTIONS ON PRODUCT USE**

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